

# Program

#	Date	Contents	Lecturer
1	17.2.	<p><b>General introduction</b></p> <ul style="list-style-type: none"> <li>• Course content</li> </ul> <p><b>Amorphous materials</b></p> <ul style="list-style-type: none"> <li>• Amorphous materials and glasses</li> <li>• Probing near- and far-range order</li> <li>• Microscopic models for hydrogen incorporation in a-Si:H</li> </ul>	FH
2	24.2.	<p><b>Conductivity, band tails</b></p> <ul style="list-style-type: none"> <li>• Conductivity mechanisms and activation energies</li> <li>• Disorder and tail states</li> <li>• Trap controlled drift conductivity</li> </ul>	FH
3	3.3.	<p><b>Optical properties</b></p> <ul style="list-style-type: none"> <li>• Dispersion and absorption</li> <li>• Crystals and bands</li> <li>• Band gaps and indirect transitions</li> <li>• Band gaps in disordered materials</li> </ul>	FH
4	10.3.	<p><b>Defect creation,</b></p> <ul style="list-style-type: none"> <li>• Defects states in a-Si:H</li> <li>• Defect creation, defect equilibrium</li> </ul> <p><b>Weak bond model</b></p> <ul style="list-style-type: none"> <li>• Bonding orbitals and band states</li> <li>• Thermal equilibrium between weak bonds and a defect</li> <li>• Defect charging and formation enthalpy</li> </ul>	FH
5	17.3.	<p><b>Processing</b></p> <ul style="list-style-type: none"> <li>• PE-CVD deposition of a-Si:H and related materials</li> <li>• Sputtering/CVD processes</li> </ul>	NW
6	24.3.	<p><b>Transport and recombination</b></p> <ul style="list-style-type: none"> <li>• Drift and diffusion transport</li> <li>• SRH recombination</li> <li>• Recombination at amphoteric defects</li> </ul>	NW
7	31.3.	<p><b>Materials for photodetectors and photoconductors</b></p> <ul style="list-style-type: none"> <li>• Primary and secondary photoconductivity</li> <li>• Photoconductivity and material quality</li> <li>• Other materials for photodetectors and thin-film solar cells</li> <li>• Xerography</li> </ul>	NW
8	7.4.	<p><b>Defect kinetics,</b></p> <ul style="list-style-type: none"> <li>• Kinetics of light-induced defect creation and defect annealing (SWE)</li> <li>• Stretched exponentials</li> </ul> <p><b>Microcrystalline silicon</b></p> <ul style="list-style-type: none"> <li>• Structural properties</li> <li>• Growth model</li> <li>• Conductivity, contact formation</li> </ul>	FH
9	14.4.	<p><b>Photovoltaics and solar cells</b></p> <ul style="list-style-type: none"> <li>• Basics of photovoltaics</li> <li>• Basics of a p-n junction solar cell</li> <li>• PV cell performance: potential and limits</li> <li>• p-n vs p-i-n junction</li> <li>• Stability issues and constraints on device design</li> <li>• Light-trapping scheme</li> <li>• Tandem devices</li> </ul>	FH

	21.4.	<b>Easter break</b>	
10	28.4.	<b>Transparent conducting oxides</b> <ul style="list-style-type: none"> <li>• Conductivity vs. transparency</li> <li>• Free carrier effects</li> <li>• Band gap narrowing, optical gap widening</li> </ul>	FH
11	5.5.	<b>Detectors (and related microelectronic) devices</b> <ul style="list-style-type: none"> <li>• Vertically integrated devices, system on glass, etc</li> <li>• Position detectors</li> <li>• Particle detectors</li> <li>• Lab on the chip</li> </ul>	NW
12	12.5.	<b>Thin-film transistors (TFT), flat panel displays (FPD) and flat panel imagers (FPI)</b> <ul style="list-style-type: none"> <li>• TFT vs FET</li> <li>• TFT operation</li> <li>• TFT configuration and fabrication</li> <li>• Material issue</li> <li>• Application of TFT for FPD, basics of FPD</li> <li>• Flat panel imagers</li> </ul>	NW
13	19.5.	<b>Emerging materials for microelectronics</b> <ul style="list-style-type: none"> <li>• Current application issues</li> <li>• Organic materials</li> <li>• Metal oxides</li> </ul> <b>Emerging applications</b>	NW
14	26.5	<b>Lab visit PV-Lab Neuchatel</b> <b>Q&amp;A</b>	FH/NW

## Oral Exam (subject to change)

### 25-30 minutes

All students will get a choice of three questions, the candidates can select two of them after one minute of reflection.

A list of formulae to be known by heart will be given to the participants before the end of the semester.

## Objectives

- Learn essential aspects of disordered semiconductors, understand the differences to crystalline ones
- Acquire an in-depth, intuitive understanding of how PV and TFT devices work
- Get insight into current issues in Macroelectronics (Materials and Applications)

## Some reference books

- Semiconductors:
  - Semiconductor devices, physics and technology, by S. M Sze, Wiley (1985)
- Optics:
  - Optical processes in Semiconductors, by J. I. Pankove, Courier Corp. (2012)
- Thin Films:
  - "Materials science of thin films" by M. Ohring (ed.) Academic Press (2002)
  - "Thin film deposition" by D. L. Smith (ed.), McGraw Hill (1995)
- Plasma:
  - "Glow Discharge Processes, Sputtering and Plasma Etching" by B. Chapman (ed.), Wiley (1980)
- Amorphous materials:
  - "The physics of amorphous materials" by S.R. Elliott (ed.) Longmann (1983)
  - "Electronic Processes in Non-crystalline Solids" by N. F. Mott and E.A. Davis (eds.) Clarendon Press (1979)
  - "Advances in Amorphous Semiconductors" by J. Singh and K. Shimikawa (eds.) Taylor & Francis (2003)
- Thin film silicon:
  - "Hydrogenated amorphous silicon" by R. Street (1991) ed. Cambridge University Press.
  - Thin-film silicon solar cells, by A. Shah (Ed.), EPFL Press (2010)
- TFT:
  - "Thin-Film Transistors" by C. R. Kagan and P. Andry (Editors), (2003) Decker, New York
- General photovoltaics:
  - "Sonnenenergie: Photovoltaik" by A. Goetzberger, Teubner, Stuttgart (1997) (in German)
  - "Crystalline Silicon Solar Cells" by A. Goetzberger, B. Voss, J. Knobloch, Wiley (1998)
  - "Solar Cells, Volumes 1-2-3", by M. A. Green, Prentice Hall (1982)
  - "Photopile Solaire", by A. Ricaud, Cahiers de Chimie, PPUR, (1997)
- On-line resource:
  - <http://pvcdrom.pveducation.org/>

### Prerequisites

A good understanding of basic semiconductor physics is required.

Please read SZE, pages 8-100 to get a good background in semiconductors !

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